



# 74LCX27 Low Voltage Triple 3-Input NOR Gate with 5V Tolerant Inputs

### **Features**

- 5V tolerant inputs
- 2.3V–3.6V V<sub>CC</sub> specifications provided
- 4.9ns  $t_{PD}$  max. ( $V_{CC} = 3.3V$ ),  $10\mu A I_{CC}$  max.
- Power down high impedance inputs and outputs
- ±24mA output drive (V<sub>CC</sub> = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds JEDEC 78 conditions
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

## **General Description**

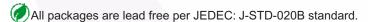
The LCX27 contains three 3-input NOR gates. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The 74LCX27 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

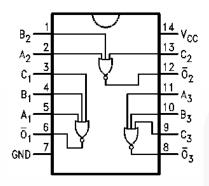
## **Ordering Information**

Order Number	Package Number	Package Description		
74LCX27M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow		
74LCX27SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide		
74LCX27MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide		

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.



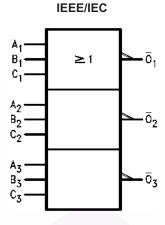
## **Connection Diagram**



## **Pin Description**

Pin Names	Description
A <sub>n</sub> , B <sub>n</sub> , C <sub>n</sub>	Inputs
$\overline{O}_n$	Outputs

## **Logic Symbol**



## **Truth Table**

$$\overline{O}_n = A_n + B_n + C_n$$

Inputs			Output
A <sub>n</sub>	B <sub>n</sub>	C <sub>n</sub>	$\overline{O}_n$
Н	Х	Х	L
Х	Н	Х	L
Х	Х	Н	L
L	L	L	Н

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V <sub>CC</sub>	Supply Voltage	-0.5V to +7.0V
V <sub>I</sub>	DC Input Voltage	-0.5V to +7.0V
Vo	DC Output Voltage, Output in HIGH or LOW State <sup>(1)</sup>	–0.5V to V <sub>CC</sub> + 0.5V
I <sub>IK</sub>	DC Input Diode Current, V <sub>I</sub> < GND	–50mA
I <sub>OK</sub>	DC Output Diode Current	
	V <sub>O</sub> < GND	–50mA
	$V_O > V_{CC}$	+50mA
Io	DC Output Source/Sink Current	±50mA
I <sub>CC</sub>	DC Supply Current per Supply Pin	±100mA
I <sub>GND</sub>	DC Ground Current per Ground Pin	±100mA
T <sub>STG</sub>	Storage Temperature	−65°C to +150°C

### Note:

## Recommended Operating Conditions<sup>(2)</sup>

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Units
V <sub>CC</sub>	Supply Voltage			
	Operating	2.0	3.6	V
	Data Retention	1.5	3.6	
V <sub>I</sub>	Input Voltage	0	5.5	V
Vo	Output Voltage, HIGH or LOW State	0	V <sub>CC</sub>	V
I <sub>OH</sub> / I <sub>OL</sub>	Output Current			
	$V_{CC} = 3.0V - 3.6V$		±24	mA
	$V_{CC} = 2.7V - 3.0V$		±12	
	$V_{CC} = 2.3V - 2.7V$		±8	
T <sub>A</sub>	Free-Air Operating Temperature	-40	85	°C
Δt / ΔV	Input Edge Rate, V <sub>IN</sub> = 0.8V–2.0V, V <sub>CC</sub> = 3.0V	0	10	ns/V

#### Note:

2. Unused inputs must be held HIGH or LOW. They may not float.

<sup>1.</sup> IO Absolute Maximum Rating must be observed.

## **DC Electrical Characteristics**

				T <sub>A</sub> = -40°C	to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min.	Max.	Units
V <sub>IH</sub>	HIGH Level Input Voltage	2.3–2.7		1.7		V
		2.7–3.6		2.0		
V <sub>IL</sub>	LOW Level Input Voltage	2.3-2.7			0.7	V
		2.7–3.6			0.8	
V <sub>OH</sub>	HIGH Level Output Voltage	2.3-3.6	$I_{OH} = -100 \mu A$	V <sub>CC</sub> - 0.2		V
		2.3	$I_{OH} = -8mA$	1.8		
		2.7	$I_{OH} = -12mA$	2.2		
		3.0	$I_{OH} = -18mA$	2.4		
			$I_{OH} = -24mA$	2.2		
V <sub>OL</sub>	LOW Level Output Voltage	2.3-3.6	$I_{OL} = 100 \mu A$		0.2	V
		2.3	I <sub>OL</sub> = 8mA		0.6	
		2.7	I <sub>OL</sub> = 12mA		0.4	
		3.0	I <sub>OL</sub> = 16mA		0.4	
			$I_{OL} = 24mA$		0.55	
I <sub>I</sub>	Input Leakage Current	2.3–3.6	$0 \le V_1 \le 5.5V$		±5.0	μA
I <sub>OFF</sub>	Power-Off Leakage Current	0	$V_I$ or $V_O = 5.5V$		10	μA
I <sub>CC</sub>	Quiescent Supply Current	2.3–3.6	$V_I = V_{CC}$ or GND		10	μA
			$3.6V \le V_I \le 5.5V$		±10	
Δl <sub>CC</sub>	Increase in I <sub>CC</sub> per Input	2.3–3.6	$V_{IH} = V_{CC} - 0.6V$		500	μA

## **AC Electrical Characteristics**

			$T_A = -4$	10°C to +	85°C, R <sub>L</sub>	= <b>500</b> Ω		
			3V ± 0.3V, 50pF		2.7V, 50pF	V <sub>CC</sub> = 2.5 C <sub>L</sub> =	5V ± 0.2V, 30pF	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Units
t <sub>PHL</sub> , t <sub>PLH</sub>	Propagation Delay	1.5	4.9	1.5	5.8	1.5	5.9	ns
toshl, toslh	Output to Output Skew <sup>(3)</sup>		1.0					ns

#### Note:

 Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>).

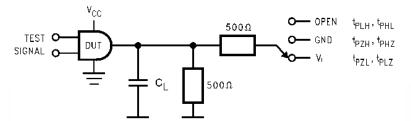
## **Dynamic Switching Characteristics**

				$T_A = 25^{\circ}C$	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Typical	Unit
V <sub>OLP</sub>	Quiet Output Dynamic Peak V <sub>OL</sub>	3.3	$C_L = 50pF, V_{IH} = 3.3V, V_{IL} = 0V$	0.8	V
		2.5	$C_L = 30 pF, V_{IH} = 2.5 V, V_{IL} = 0 V$	0.6	
V <sub>OLV</sub>	Quiet Output Dynamic Valley V <sub>OL</sub>	3.3	$C_L = 50 pF, V_{IH} = 3.3 V, V_{IL} = 0 V$	-0.8	V
		2.5	$C_L = 30pF, V_{IH} = 2.5V, V_{IL} = 0V$	-0.6	

## Capacitance

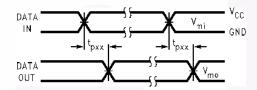
Symbol	Parameter	Conditions	Typical	Units
C <sub>IN</sub>	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	8	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$ , $f = 10MHz$	25	pF

## AC Loading and Waveforms (Generic for LCX Family)

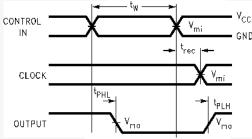


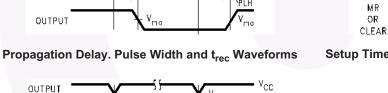
Test	Switch
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
$t_{PZL}, t_{PLZ}$	6V at $V_{CC} = 3.3 \pm 0.3V$ $V_{CC} \times 2$ at $V_{CC} = 2.5 \pm 0.2V$
$t_{PZH},t_{PHZ}$	GND

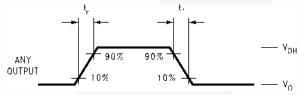
Figure 1. AC Test Circuit (C<sub>L</sub> includes probe and jig capacitance)



### **Waveform for Inverting and Non-Inverting Functions**







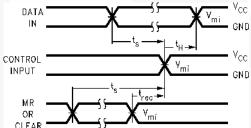
 $t_{\text{rise}}$  and  $t_{\text{fall}}$ 

### 3-STATE Output Low Enable and **Disable Times for Logic**

	V <sub>CC</sub>		
Symbol	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V <sub>mi</sub>	1.5V	1.5V	V <sub>CC</sub> /2
V <sub>mo</sub>	1.5V	1.5V	V <sub>CC</sub> /2
V <sub>x</sub>	V <sub>OL</sub> + 0.3V	V <sub>OL</sub> + 0.3V	V <sub>OL</sub> + 0.15V
V <sub>y</sub>	V <sub>OH</sub> – 0.3V	V <sub>OH</sub> – 0.3V	V <sub>OH</sub> – 0.15V

Figure 2. Waveforms (Input Characteristics; f = 1MHz,  $t_r = t_f = 3ns$ )

### 3-STATE Output High Enable and **Disable Times for Logic**



Setup Time, Hold Time and Recovery Time for Logic

CONTROL

DATA

OUT

t<sub>PZL</sub>

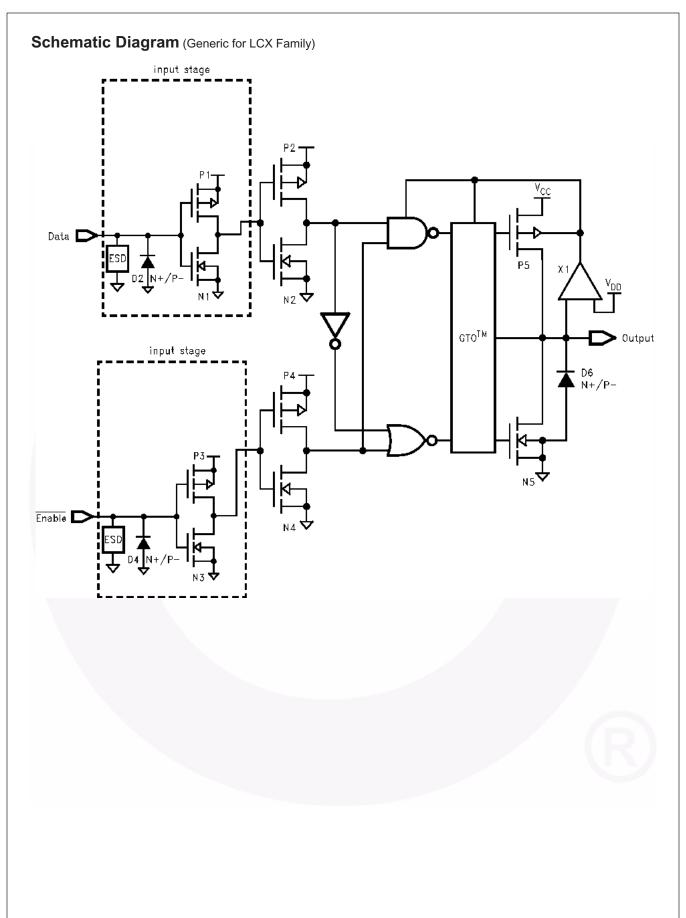




Figure 3. 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow

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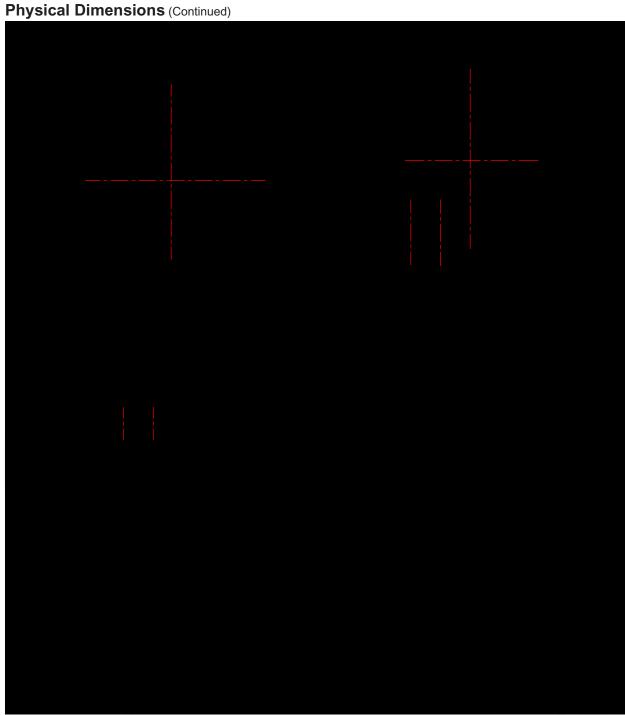
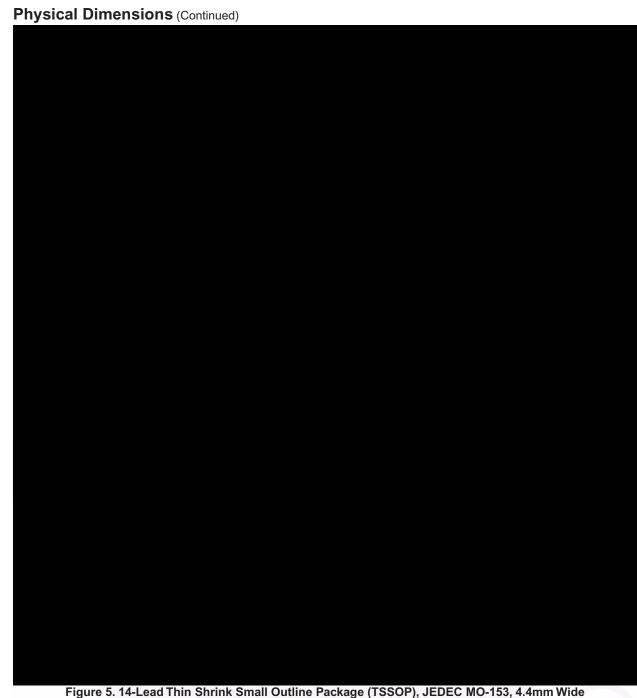


Figure 4. 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide

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